ASSP Dual Serial Input PLL FrequencySynthesizer MB15F03L

■ DESCRIPITON

The Fujitsu MB15F03L is a serial input Phase Locked Loop (PLL) frequency synthesizer with a 1800MHz and a 250MHz prescalers. A 64/65 or a 128/129 for the 1800MHz prescaler, and a 16/17 or a 32/33 for 250MHz prescaler can be selected that enables pulse swallow operation.

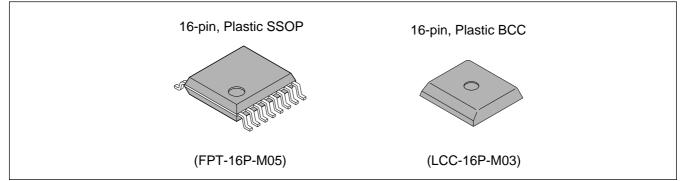
The latest BiCMOS process technology is used, resultantly a supply current is limited as low as 5.0mA typ. at a supply voltage of 3.0V.

Furthermore, a super charger circuit is included to provide a fast tuning as well as low noise performance. As a result of this, MB15F03L is ideally suitable for digital mobile communications, such as PHS(Personal Handy Phone System), PCN (Personal Communication Network) and PCS(Personal Communication Service).

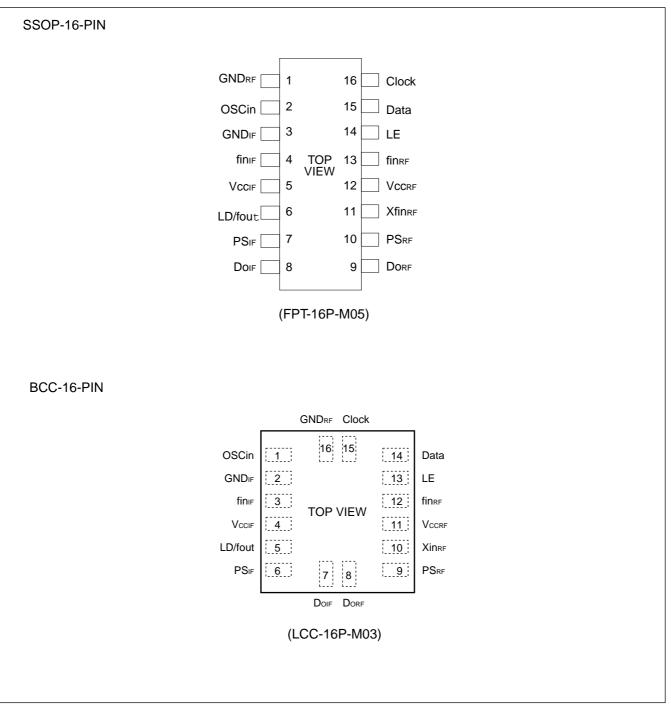
■ FEATURES

- High frequency operation RF synthesizer: 1800MHz max. / IF synthesizer: 250MHz max.
- Low power supply voltage: Vcc = 2.7 to 3.6V
- Very Low power supply current : Icc = 5.0 mA typ. (Vcc = 3V)
- Power saving function : Supply current at power saving mode Typ.0.1μA (Vcc=3V), Max.10μA (IPs1=IPs2)
- Dual modulus prescaler : 1800MHz prescaler(64/65,128/129) , 250MHz prescaler(16/17,32/33)
- Serial input 14-bit programmable reference divider: R = 5 to 16,383
- Serial input 18-bit programmable divider consisting of:
 - Binary 7-bit swallow counter: 0 to 127
 - Binary 11-bit programmable counter: 5 to 2,047
- On-chip high performance charge pump circuit and phase comparator, achieving high-speed lock-up and low phase noise
- On-chip phase control for phase comparator
- Wide operating temperature: Ta = -40 to 85°C

PACKAGE



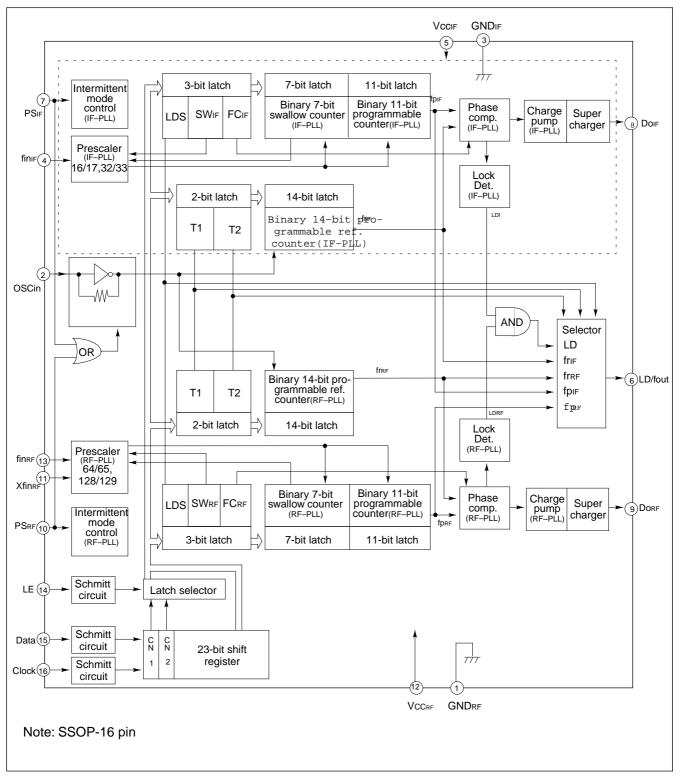
■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin	No.	Pin		Descriptions
SSOP-16	BCC-16	name	I/O	Descriptions
1	16	GNDrf	_	Ground for RF–PLL section.
2	1	OSCin	I	The programmable reference divider input. TCXO should be connected with a AC coupling capacitor.
3	2	GNDIF	_	Ground for the IF-PLL section.
4	3	finif	I	Prescaler input pin for the IF-PLL. The connection with VCO should be AC coupling.
5	4	Vccif	_	Power supply voltage input pin for the IF-PLL section.
6	5	LD/fout	0	Lock detect signal output (LD) / phase comparator monitoring output (fout) The output signal is selected by a LDS bit in a serial data. LDS bit = "H" ; outputs fout signal LDS bit = "L" ; outputs LD signal
7	6	PSIF	I	Power saving mode control for the IF-PLL section. This pin must be set at "L" Power-ON. (Open is prohibited.) PSIF = "H"; Normal mode PSIF = "L"; Power saving mode
8	7	Doif	0	Charge pump output for the IF-PLL section. Phase characteristics of the phase detector can be reversed by FC-bit.
9	8	Dorf	0	Charge pump output for the RF-PLL section. Phase characteristics of the phase detector can be reversed by FC-bit.
10	9	PSrf	I	Power saving mode control for the RF-PLL section. This pin must be set at "L" Power-ON. (Open is prohibited.) PSRF = "H"; Normal mode PSRF = "L"; Power saving mode
11	10	Xfinrf	I	Prescaler complimentary input for the RF-PLL section. This pin should be grounded via a capacitor.
12	11	VCCRF	_	Power supply voltage input pin for the RF-PLL section, the shift register and the oscillator input buffer. When power is OFF, latched data of RF- PLL is cancelled.
13	12	finrf	I	Prescaler input pin for the RF-PLL. The connection with VCO should be AC coupling.
14	13	LE	I	Load enable signal input (with the schmitt trigger circuit.) When LE is "H", data in the shift register is transferred to the corresponding latch according to the control bit in a serial data.
15	14	Data	I	Serial data input (with the schmitt trigger circuit.) A data is transferred to the corresponding latch (IF-ref counter, IF-prog. counter, RF-ref. counter, RF-prog. counter) according to the control bit in a serial data.
16	15	Clock	I	Clock input for the 23-bit shift register (with the schmitt trigger circuit.) One bit data is shifted into the shift register on a rising edge of the clock.

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rating	Unit	Remark
Power supply voltage	Vcc	-0.5 to +4.0	V	
Input voltage	Vi	-0.5 to Vcc +0.5	V	
Output voltage	Vo	-0.5 to Vcc +0.5	V	
	lo	-10 to +10	mA	Except Do
Output current	Ido	-25 to +25	mA	Do output
Storage temperature	Тѕтс	-55 to +125	°C	

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Value		Unit	Note
Faianetei	Symbol	Min	Тур	Max	Unit	Note
Power supply voltage	Vcc	2.7	3.0	3.6	V	VCCIF=VCCRF
Input voltage	Vi	GND	_	Vcc	V	
Operating temperature	Та	-40	_	+85	°C	

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always yse semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with repect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

Handling Precautions

- This device should be transported and stored in anti-static containers.
- This is a static-sensitive device; take proper anti-ESD precautions. Ensure that personnel and equipment are properly grounded. Cover workerbenches with grounded conductive mats.
- Always turn the power supply off before inserting or removing the device from its socket.
- Protect leads with a conductive sheet when handling or transporting PC boards with devices.

ELECTRICAL CHARACTERISTICS

(Vcc=2.7V to 3.6V, Ta=-40°C to 85°C)

			0 14	(*	Value	3.6V, 1a=-40°0	′
Paramete	er	Symbol	Condition	Min.	Тур.	Max.	Unit
Power supply sur	ront		finı⊧ = 233.15MHz, fosc = 12MHz	—	1.5	_	mA
Power supply cur	ent	ICCRF ^{*2}	finrr = 1800MHz, fosc = 12MHz	_	3.5	_	- MA
Power saving curr	ront	Ipsif	Vccı⊧ current at PSı⊧ ="L"	_	0.1 ^{*3}	10	μA
rower saving cur	ent	Ipsrf	VccrF current at PSIF/RF ="L"	_	0.1 ^{*3}	10	μΑ
	finiF ^{*4}	finı⊧	IF-PLL	50	—	250	
Operating frequency	finrf*4	finrf	RF–PLL	100	—	1800	MHz
	OSCin	fosc	_	3	_	40	
	finif	Vfinif	IF–PLL, 50Ω termination	-10	_	+2	dBm
Input sensitivity	finrf	Vfinrf	RF–PLL, 50Ω termination	-10	_	+2	dBm
	OSCin	Vosc	_	0.5	_	Vcc	Vp-p
	Data,	Vін	Schmitt trigger input	Vccx0.7+ 0.4	_	_	v
Input voltage	Clock, LE	VIL	Schmitt trigger input	_	_	Vccx0.3 -0.4	V
	PSIF,	Vін	—	Vccx0.7	—	_	V
	PSrf	VIL	—	_	_	Vccx0.3	
	Data,	IIH ^{*5}	—	-1.0		+1.0	
Input current	Clock, LE, PSif, PSrf	lı∟*5	_	-1.0	_	+1.0	μΑ
	OSCin	Ін	—	0	_	+100	
	OSCin	IIL ^{*5}	—	-100	_	0	μA
		Vон	Іон=–1.0mA	Vcc-0.4	—	_	V
Output voltage	LD/fout	Vol	lo∟= 1.0mA	_	_	0.4	
	Doif,	Vdoh	Іоон =-1.0mA	Vcc-0.4	—	_	V
	DORF	Vdol	Vcc=3.0V, IDOL=1.0mA	_	—	0.4	V
High impedance cutoff current	Doif, Dorf	IOFF	Vcc=3.0V, Voff=GND to Vcc			3.0	nA

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(Vcc=2.7V to 3.6V, Ta=-40°C to 85°C)

Paramete	~r	Symbol	Condition			Unit	
Falamete	51	Symbol	Condition	Min.	Тур.	Max.	Unit
	LD/fout	Ioн⁺⁵	Vcc = 3.0V	-1.0	—	—	mA
	LD/IOUI	lol	Vcc = 3.0V			1.0	
Output current	Doif,	IDOH ^{*5}	Vcc = 3.0V, Vрон = 2.0V , Ta=25°С	-11		-6	mA
	Dorf	Idol	Vcc = 3.0V, VDOL = 1.0V, Ta=25°C	8		15	

*1: Conditions ; VCCIF = 3V, Ta = 25° C, in locking state.

*2: Conditions ; VCCRF = 3V, Ta = 25°C, in locking state.

*3: fosc = 12.8 MHz , Vcc = 3.0V, Ta = $25^{\circ}C$

*4: AC coupling with a 1000pF capacitor connected.

*5: The symbol "-"(minus) means direction of current flow.

FUNCTIONAL DESCRIPTIONS

The divide ratio can be calculated using the following equation:

 $f_{VCO} = \{(P \times N) + A\} \times f_{OSC} \div R \quad (A < N)$

fvco: Output frequency of external voltage controlled oscillator (VCO)

P: Preset divide ratio of dual modulus prescaler (16 or 32 for IF-PLL, 64 or 128 for RF-PLL)

N: Preset divide ratio of binary 11-bit programmable counter (5 to 2,047)

A: Preset divide ratio of binary 7-bit swallow counter ($0 \le A \le 127$)

fosc: Reference oscillation frequency

R: Preset divide ratio of binary 14-bit programmable reference counter (5 to 16,383)

Serial Data Input

Serial data is entered using three pins, Data pin, Clock pin, and LE pin. Programmable dividers of IF/RF–PLL sections, programmable reference dividers of IF/RF PLL sections are controlled individually. Serial data of binary data is entered through Data pin.

On rising edge of clock, one bit of serial data is transferred into the shift register. When load enable signal is high, the data stored in the shift register is transferred to one of latch of them depending upon the control bit data setting.

Con	trol bit	Destination of serial data
CN1	CN2	
L	L	The programmable reference counter for the IF-PLL.
Н	L	The programmable reference counter for the RF-PLL.
L	Н	The programmable counter and the swallow counter for the IF-PLL
Н	Н	The programmable counter and the swallow counter for the RF-PLL

Table1. Control Bit

Shift Register Configuration

LSE ↓	3	Data Flow																				
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
C N 1	C N 2	Т 1	T 2	R 1	R 2	R 3	R 4	R 5	R 6	R 7	R 8	R 9	R 10	R 11	R 12	R 13	R 14	x	x	х	x	x
CN1, R1 to T1, 2 X Note) R14	4	: Div : Tes : Dui	t pui mmy	atio pos bits	e bit (Set	"0"	or "1		e pro	ogra	mma	able	refe	renc	e co	unte	er (5	to 16	6,38	3)	[Tab [Tab [Tab

	Pro	gram	mabl	e Co	unte	r																
LSB		Data Flow MSB																				
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
C N	C N	L D	S W	F C	A 1	A 2	А 3	A 4	A 5	A 6	A 7	N 1	N 2	N 3	N 4	N 5	N 6	N 7	N 8	N 9	N 10	N 11
1	2	S	IF/RF	IF/RF																		
		CN1	, 2	: C	Contro	ol bit														[Tabl	e. 1]	
		N1 to	o N11	: C	Divide	ratio	settir	ng bits	s for t	he pro	ogran	nmab	le cou	Inter	(5 to 2	2,047)			[Tab	e. 4]	
		A1 to	5 A7	: C	Divide	ratio	settir	ng bits	s for t	he sw	allow	cour	ter (0	to 12	27)					[Tab	le. 5]	
		SWIF	/RF	: C (Divide 16/17	ratio or 32	settir 2/33 f	ng bit or the	for th	e pre LL, 64	scale 4/65 d	r or 128	8/129	for th	e RF·	-PLL)				[Tabl	le. 6]	
		FCIF/	RF	: F	hase	e cont	rol bit	for th	ne pha	ase d	etecto	or								[Tab	le. 7]	
		LDS : LD/fout signal select bit [Table. 8]																				
		Note	e: Da	ata inj	put w	vith N	ISB f	irst.														

Table2. Binary 14-bit Programmable Reference Counter Data Setting

Divide ratio (R)	R 14	R 13	R 12	R 11	R 10	R 9	R 8	R 7	R 6	R 5	R 4	R 3	R 2	R 1
5	0	0	0	0	0	0	0	0	0	0	0	1	0	1
6	0	0	0	0	0	0	0	0	0	0	0	1	1	0
•	•	•	•	•	•	•	•	•	•	•	•	•	•	•
16383	1	1	1	1	1	1	1	1	1	1	1	1	1	1

Note: • Divide ratio less than 5 is prohibited.

Table.3 Test Purpose Bit Setting

Т 1	T 2	LD/fout pin state
L	L	Outputs friF.
н	L	Outputs frRF.
L	Н	Outputs fpiF.
Н	Н	Outputs fprr.

Divide ratio (N)	N 11	N 10	N 9	N 8	N 7	N 6	N 5	N 4	N 3	N 2	N 1
5	0	0	0	0	0	0	0	0	1	0	1
6	0	0	0	0	0	0	0	0	1	1	0
•	•	•	•	•	•	•	•	•	•	•	•
2047	1	1	1	1	1	1	1	1	1	1	1

Table.4 Binary 11-bit Programmable Counter Data Setting

Note: • Divide ratio less than 5 is prohibited.

Table.5 Binary 7-bit Swallow Counter Data Setting

Divide ratio (A)	A 7	A 6	A 5	A 4	A 3	A 2	A 1
0	0	0	0	0	0	0	0
1	0	0	0	0	0	0	1
•	•	•	•	•	•	•	•
127	1	1	1	1	1	1	1

Note: • Divide ratio (A) range = 0 to 127

Table. 6 Prescaler Data Setting

		SW = "H"	SW = "L"
Prescaler divide ratio	IF-PLL	16/17	32/33
	RF-PLL	64/65	128/129

Table. 7 Phase Comparator Phase Switching Data Setting

	FCIF,RF = H	FCIF,RF = L		
	DOIF,RF	Doif,rf		
fr > fp	Н	L		
fr = fp	Z	Z		
fr < fp	L	Н		
VCO polarity	(1)	(2)		

Note: • Z = High-impedance

• Depending upon the VCO and LPF polarity, FC bit should be set.

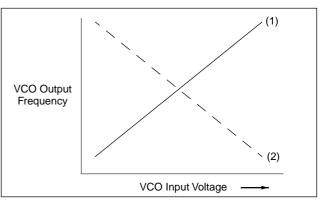
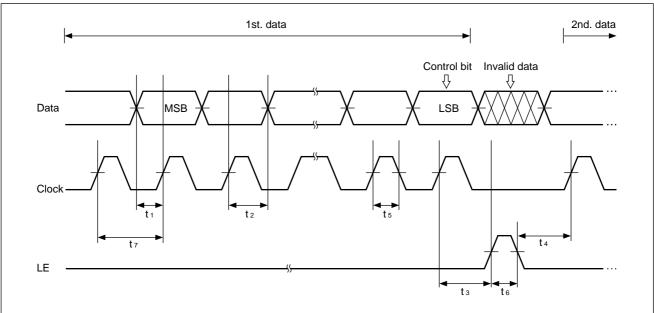


Table. 8 LD/fout Output Select Data Setting

LDS	LD/fout output signal	
Н	fout (frif/Rf, fpif/Rf) signals	
L	LD signal	

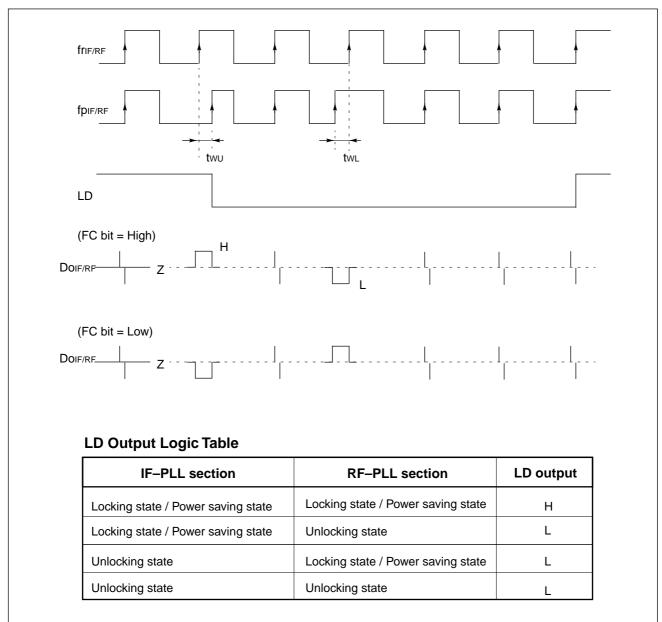
Serial Data Input Timing



On rising edge of the clock, one bit of the data is transferred into the shift register.

Parameter	Min	Тур	Max	Unit	Parameter	Min	Тур	Max	Unit
t1	20	—	_	ns	t5	30	—	-	ns
t2	20	_	-	ns	t6	100	_	Ι	ns
t3	30	-	_	ns	t7	100	_	-	ns
t4	20	_	_	ns					





Note: •Phase error detection range = -2π to $+2\pi$

•Pulses on DOIF/RF signals are output to prevent dead zone.

•LD output becomes low when phase error is two or more.

•LD output becomes high when phase error is tw∟ or less and continues to be so for three cycles or more. •tw∪ and tw∟ depend on OSCin input frequency as follows.

 $twu \ge 4/fosc:$ i.e. $twu \ge 312.5$ ns when foscin = 12.8 MHz

twL \leq 8/fosc: i.e. twL \leq 625.0ns when foscin = 12.8 MHz

■ POWER SAVING MODE (INTERMITTENT MODE CONTROL CIRCUIT)

Setting a PS_{IF(RF)} pin to Low, IF-PLL (RF-PLL) enters into power saving mode resultant current consumption can be limited to $10\mu A$ (typ.). Setting PS pin to High, power saving mode is released so that the device works normally.

In addition, the intermittent operation control circuit is included which helps smooth start up from stand by mode. In general, the power consumption can be saved by the intermittent operation that powering down or waking up the synthesizer. Such case, if the PLL is powered up uncontrolled, the resulting phase comparator output signal is unpredictable due to an undefined phase relation between reference frequency (fr) and comparison frequency (fp) and may in the worst case take longer time for lock up of the loop.

To prevent this, the intermittent operation control circuit enforces a limited error signal output of the phase detector during power up. Thus keeping the loop locked.

PS pin must be set "L" at Power-ON.

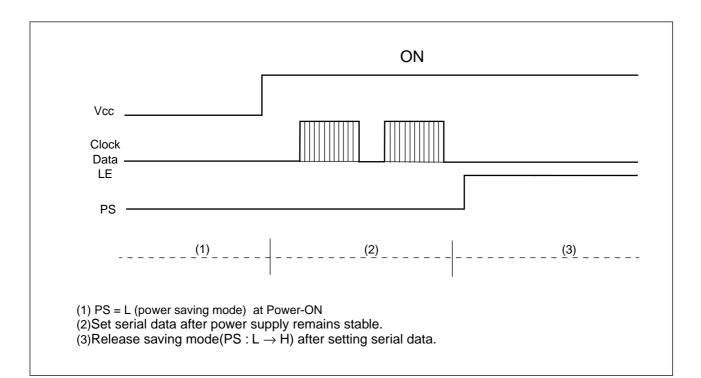
Allow 1 µs after frequency stabilization on power-up for exiting the power saving mode (PS: L to H) Serial data can be entered during the power saving mode.

During the power saving mode, the corresponding section except for indispensable circuit for the power saving function stops working, then current consumption is reduced to $10\mu A$ per one PLL section.

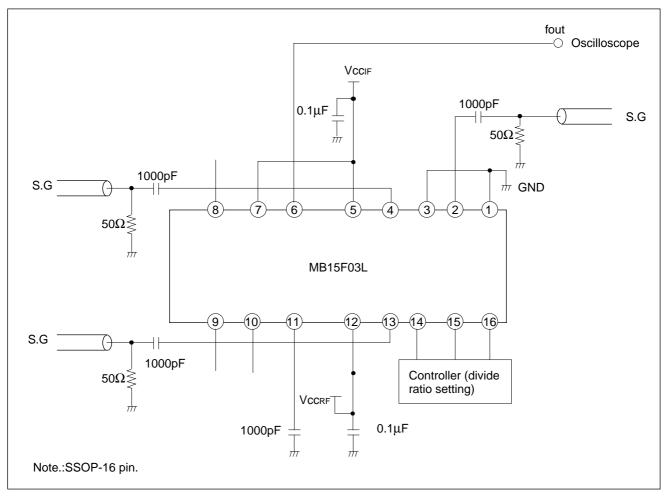
At that time, the Do and LD become the same state as when a loop is locking. That is, the Do becomes high impedance.

A VCO control voltage is naturally kept at the locking voltage which defined by a LPF's time constant. As a result of this, VCO's frequency is kept at the locking frequency.

PSIF	PSRF	IF-PLL counters	RF-PLL counters	OSC input buffer
L	L	OFF	OFF	OFF
Н	L	ON	OFF	ON
L	Н	OFF	ON	ON
Н	Н	ON	ON	ON

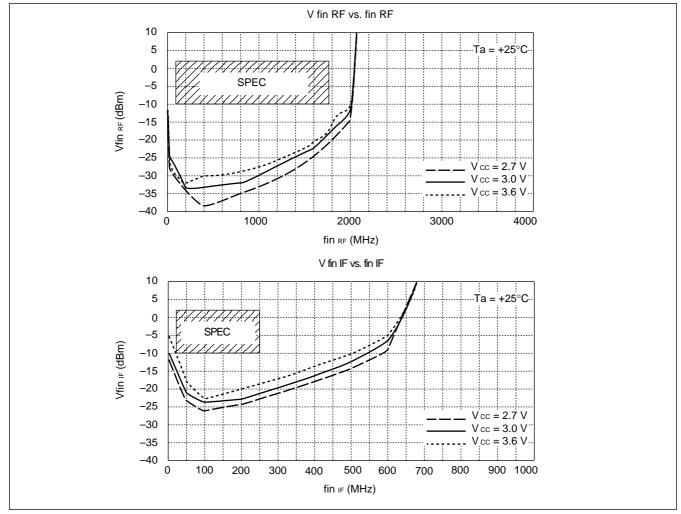




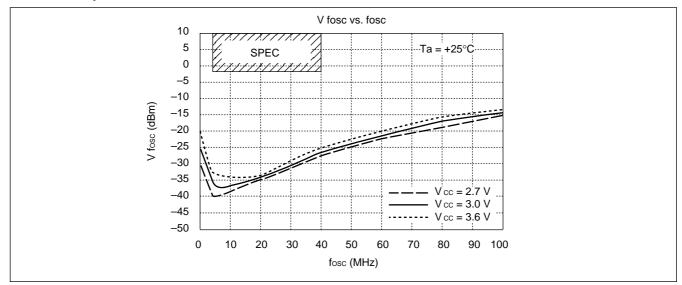


■ TYPICAL CHARACTERISITICS

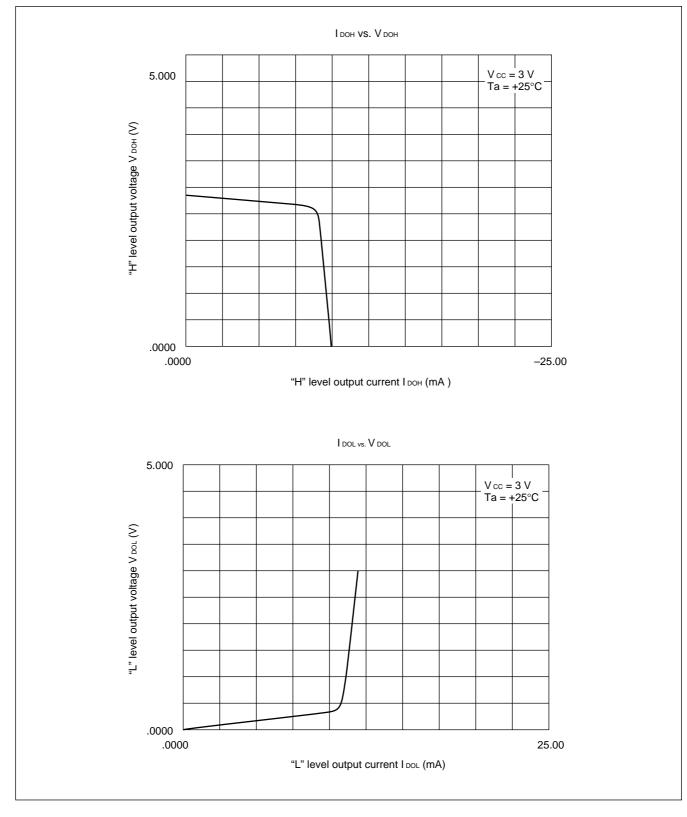
1. fin Input Sensitivity



2. OSCin Input Characteristics

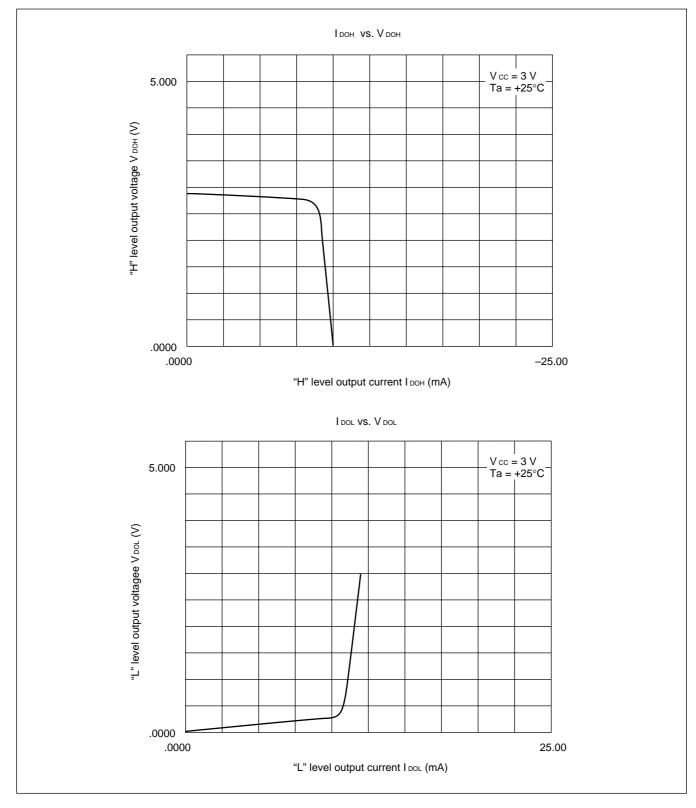


3. Dorr Output Current

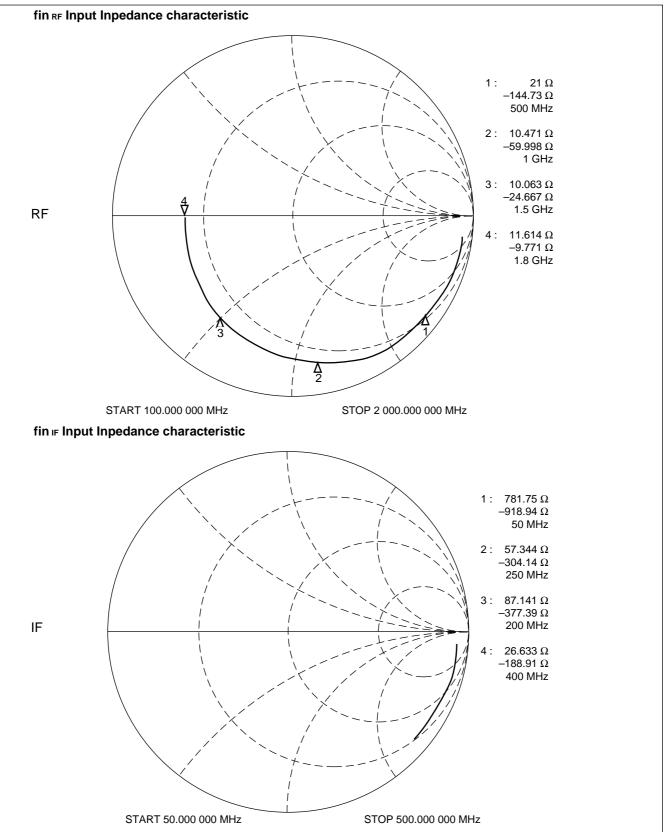


MB15F03L

4. DoiF Output Current

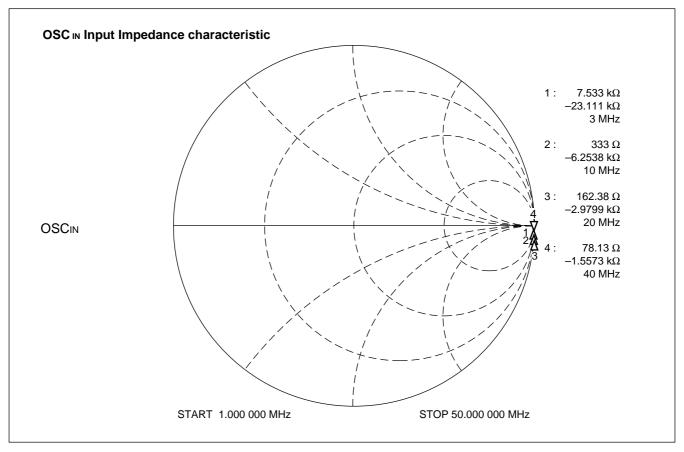


5. Input Impedance.

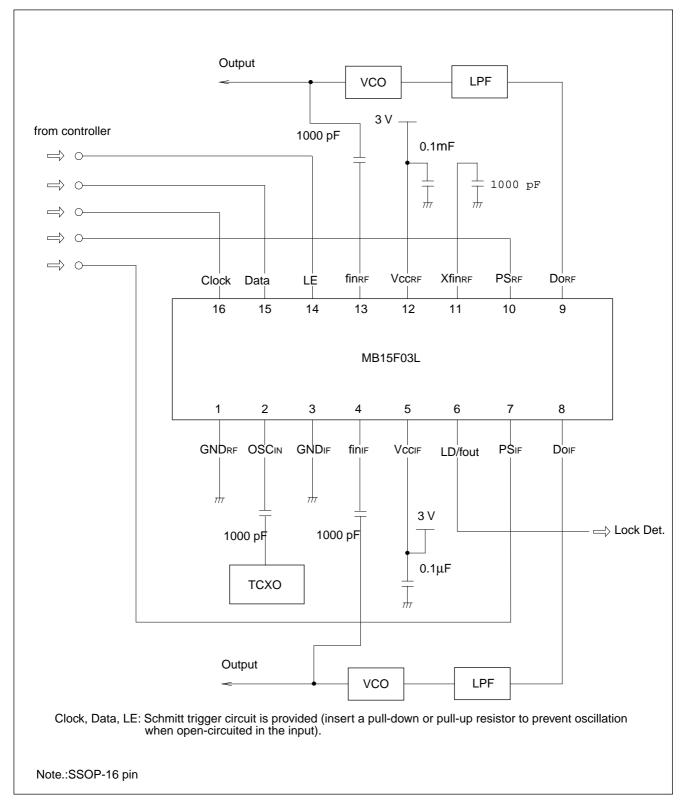


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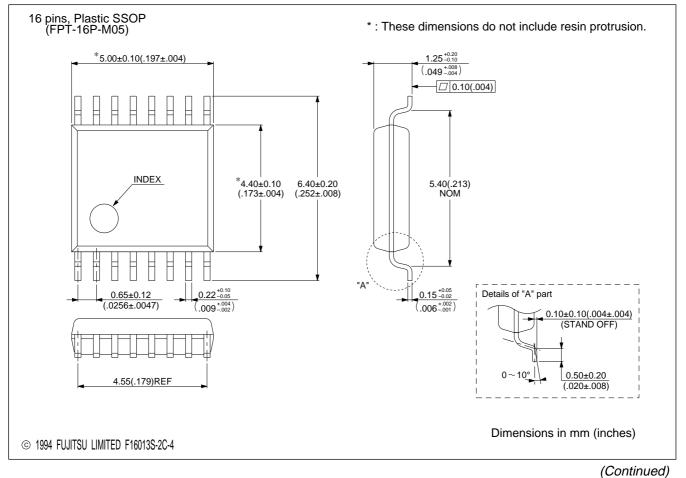
■ APPLICATION EXAMPLE



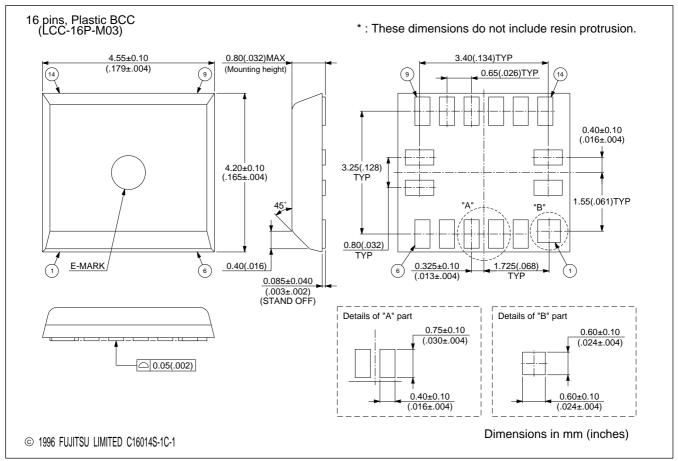
■ ORDERING INFORMATION

Part number	Package	Remarks
MB15F03L PFV	16pin, Plastic SSOP (FPT-16P-M05)	
MB15F03L PV	16pin, Plastic BCC (LCC-16P-M03)	

PACKAGE DIMENSION



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MB15F03L

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